

This Page Is Inserted by IFW Operations
and is not a part of the Official Record

BEST AVAILABLE IMAGES

Defective images within this document are accurate representations of the original documents submitted by the applicant.

Defects in the images may include (but are not limited to):

- BLACK BORDERS
- TEXT CUT OFF AT TOP, BOTTOM OR SIDES
- FADED TEXT
- ILLEGIBLE TEXT
- SKEWED/SLANTED IMAGES
- COLORED PHOTOS
- BLACK OR VERY BLACK AND WHITE DARK PHOTOS
- GRAY SCALE DOCUMENTS

IMAGES ARE BEST AVAILABLE COPY.

As rescanning documents *will not* correct images,
please do not report the images to the
Image Problem Mailbox.

?t 5/5/1

09/914050

5/5/1

DIALOG(R) File 351:Derwent WPI
(c) 2001 Derwent Info Ltd. All rts. reserv.

JCO3
JCO3 Rec'd PCT/TTO

22 AUG 2001

013396251 **Image available**

WPI Acc No: 2000-568189/200053

XRPX Acc No: N00-419721

Electro-optical apparatus e.g. LCD device has group of driving and pixel electrodes on layer insulation film opposing each other and connected through through-holes

Patent Assignee: SEIKO EPSON CORP (SHIH.)

Number of Countries: 001 Number of Patents: 001

Patent Family:

Patent No	Kind	Date	Applicat No	Kind	Date	Week
JP 2000221529	A	20000811	JP 9925014	A	19990202	200053 B

Priority Applications (No Type Date): JP 9925014 A 19990202

Patent Details:

Patent No	Kind	Lan	Pg	Main IPC	Filing Notes
JP 2000221529	A	8		G02F-001/1343	

Abstract (Basic): JP 2000221529 A

NOVELTY - A layer insulation film (18) is formed on opposing internal side surface of substrate (12). Pixel electrodes (15A-15C) are respectively formed on the surface area of film (18) in which driving electrode group (14A-14C) oppose scanning electrode (16). The driving and pixel electrodes are connected through through-holes (19A-19C) formed on film (18).

USE - For e.g. reflecting type LCD device and electroluminescent display device.

ADVANTAGE - The number of electrodes which perform multiplexing is increased. Hence electro-optical apparatus with favorable display quality is provided.

DESCRIPTION OF DRAWING(S) - The figure shows the sectional view of LCD device.

Substrate (12)

Pixel electrodes (15A-15C)

Scanning electrode (16)

Layer insulation film (18)

Through-holes (19A-19C)

pp; 8 DwgNo 2/10

Title Terms: ELECTRO; OPTICAL; APPARATUS; LCD; DEVICE; GROUP; DRIVE; PIXEL; ELECTRODE; LAYER; INSULATE; FILM; OPPOSED; CONNECT; THROUGH; THROUGH; HOLE

Derwent Class: P81; P85; U14

International Patent Class (Main): G02F-001/1343

International Patent Class (Additional): G09F-009/30

File Segment: EPI; EngPI

BEST AVAILABLE COPY

(19)



JAPANESE PATENT OFFICE

PATENT ABSTRACTS OF JAPAN

(11) Publication number: 2000221529 A

(43) Date of publication of application: 11 . 08 . 00

(51) Int. Cl

G02F 1/1343
G09F 9/30

(21) Application number: 11025014

(71) Applicant: SEIKO EPSON CORP

(22) Date of filing: 02 . 02 . 99

(72) Inventor: IINO SEIICHI

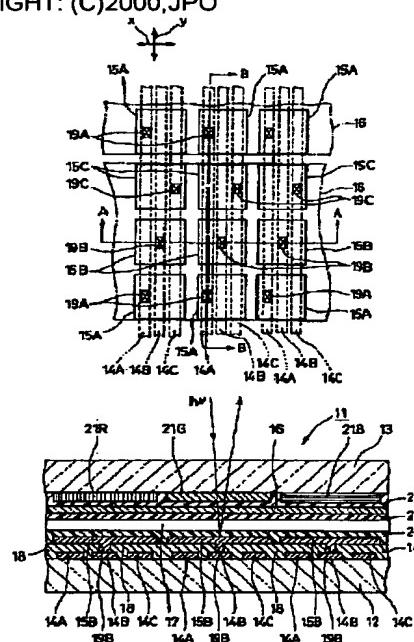
(54) ELECTRO-OPTIC DEVICE

display quality can be improved.

(57) Abstract:

PROBLEM TO BE SOLVED: To provide an electro-optic device having good display quality with a high aperture ratio by increasing the number of the electrodes to be multiplexed.

SOLUTION: Plural scanning electrodes 16 formed in a stripe form are formed along a row direction on a front glass substrate 13 side and drive electrodes 14A, 14B and 14C constituting three groups are formed along a column direction on a rear glass substrate 12 side. Interlayer insulating films 18 are formed on the opposite inner flank of the rear glass substrate 12 formed with the drive electrodes. Respective three pixel electrodes 15A, 15B and 15C are formed along the column direction on the surfaces of the interlayer insulating film 18 of the regions where the drive electrode groups face the scanning electrodes 16. The drive electrodes 14A, 14B and 14C corresponding to these pixel electrodes 15A, 15B and 15C are connected via through-holes 19A, 19B and 19C formed on the interlayer insulating films 18. Since the aperture ratio of the pixel electrodes 15 can be greatly improved and the number of the drive electrodes can be increased by such constitution, the drive controllability and the



(19)日本国特許庁 (JP)

(12) 公開特許公報 (A)

(11)特許出願公開番号
特開2000-221529
(P2000-221529A)

(43)公開日 平成12年8月11日(2000.8.11)

(51) Int.Cl. ⁷	識別記号	F I	マーク(参考)
G 0 2 F 1/1343		G 0 2 F 1/1343	2 H 0 9 2
G 0 9 F 9/30	3 4 3	G 0 9 F 9/30	3 4 3 C 5 C 0 9 4

審査請求 未請求 請求項の数 5 O L (全 8 頁)

(21)出願番号 特願平11-25014

(22)出願日 平成11年2月2日(1999.2.2)

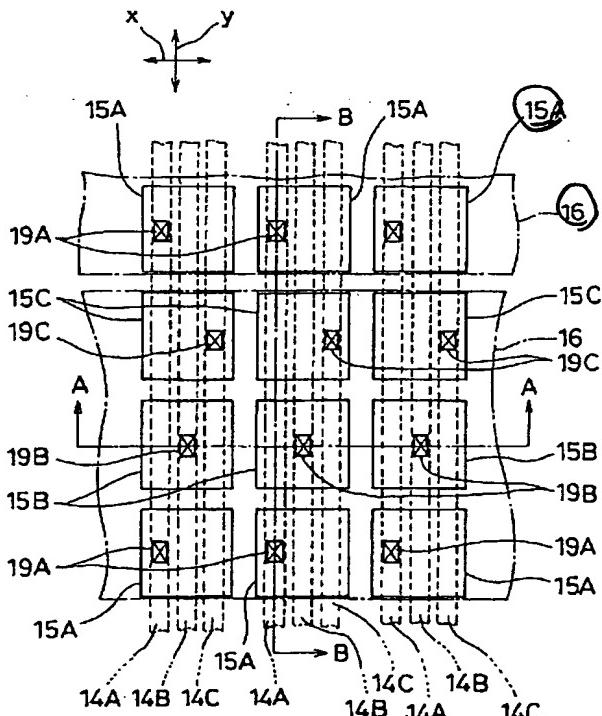
(71)出願人 000002369
セイコーエプソン株式会社
東京都新宿区西新宿2丁目4番1号
(72)発明者 飯野 聖一
長野県諏訪市大和3丁目3番5号 セイコ
ーエプソン株式会社内
(74)代理人 100093388
弁理士 鈴木 喜三郎 (外2名)
F ターム(参考) 2H092 GA07 GA25 GA29 HA03 HA05
MA05 MA13 MA17 NA07
5C094 AA01 AA10 BA27 BA43 CA19
DA14 DB04 EA02 EA04 EA05
EA07

(54)【発明の名称】電気光学装置

(57)【要約】

【課題】多重化された電極数を増加し高開口率で表示品質の良好な電気光学装置を提供する。

【解決手段】前ガラス基板13側にストライプ状に形成された複数の走査電極16が行方向に沿って形成され、後ガラス基板12側に3本の群をなす駆動電極14A、14B、14Cが列方向に沿って形成され、駆動電極を形成した後ガラス基板12の対向内側面に層間絶縁膜18が形成されている。駆動電極群が走査電極16と対向する領域の層間絶縁膜18の表面にそれぞれ3つの画素電極15A、15B、15Cが列方向に沿って形成され、これらの画素電極15A、15B、15Cに対応する駆動電極14A、14B、14Cが層間絶縁膜18に形成したスルーホール19A、19B、19Cを介して接続されている。このような構成により、画素電極15の開口率を大幅に向上できるとともに、駆動電極数を増やすことができるため駆動制御性や表示品質を向上できる。



【特許請求の範囲】

【請求項1】 相対向して対をなす第1の基板と第2の基板のうち、少なくとも一方が表示用光に対して透過性を有し、前記第1の基板の対向内側面に所定方向に沿って互いに平行をなす複数本で群を構成する第1の電極が複数群、互いに略平行に形成され、かつ前記第2の基板の対向内側面に前記第1の電極に交差する方向に沿って互いに略平行な複数の第2の電極が形成され、前記第1の基板と前記第2の基板との間に電気光学材料層が介在された電気光学装置であって、
前記第1の電極を含む前記第1の基板の対向内側面に層間絶縁膜が形成され、前記第2の電極と前記第1の電極の群との、それぞれの交差位置における前記層間絶縁膜の表面に、前記群を構成する前記第1の電極と同数の画素電極の群が、前記第2の電極と対向するように配置、形成され、かつ前記第1の電極の群の延在方向に沿って前記画素電極の群が列をなすとともに、それぞれの前記交差位置で、前記画素電極の群と前記第1の電極の群のうちのそれぞれ対応するものどうしが、前記層間絶縁膜に形成されたスルーホールを介して接続されていることを特徴とする電気光学装置。

【請求項2】 前記電気光学材料層は、液晶であることを特徴とする請求項1記載の電気光学装置。

【請求項3】 前記画素電極は表示用光に対して反射性を有する導電性材料で形成され、前記第2の基板および前記第2の電極は表示用光に対して透過性を有することを特徴とする請求項2記載の電気光学装置。

【請求項4】 前記画素電極、前記層間絶縁膜、前記第1の電極、前記第1の基板、前記第2の基板、および前記第2の電極は、表示用光に対して透過性を有するとともに、前記第1の基板の後方に照明手段を備えることを特徴とする請求項2記載の電気光学装置。

【請求項5】 前記第1の電極は駆動電極であり、前記第2の電極は走査電極であることを特徴とする請求項1ないし請求項4のいずれかに記載の電気光学装置。

【発明の詳細な説明】

【0001】

【発明の属する技術分野】 本発明は電気光学装置に関し、さらに詳しくは多重マトリクス構成された電極構造を有する液晶表示装置、エレクトロルミネッセンス(EL)ディスプレなどの電気光学装置に関する。

【0002】

【従来の技術】 従来、電極が多重マトリクス構成された電気光学装置としては、図8～図10に示すような二重マトリクス構成の液晶表示装置1が知られている。図8は液晶表示装置の電極パターンを示す平面図、図9は図8のE-E断面図、図10は図8のF-F断面図である。図9および図10に示すように、この液晶表示装置1は相対向するガラス基板2、3を有している。

【0003】 ガラス基板2におけるガラス基板3と対向

10

20

30

40

50

する面には、表示領域を縦断する方向に延在された複数対の駆動電極4A、4Bが平行に形成されている。これら駆動電極4A、4Bは、例えばアルミニウムなどの光反射性を有する導電性材料で形成されている。図8に示すように、駆動電極4Aは、矩形状の画素電極部4APと幅の狭い電極線部4ALとが延在方向に沿って交互に配置された略櫛歯形状に形成されており、対をなす駆動電極4Bに向けて凹凸が形成されている。すなわち、凹部が電極線部4ALが形成された部分に相当し、凸部が画素電極部4APが形成された部分に相当する。同様に駆動電極4Bも、対をなす駆動電極4Aに向けて凹凸をなすように、矩形状の画素電極部4BPと幅の狭い電極線部4BLとが延在方向に沿って交互に配置された略櫛歯形状に形成されている。これら一対をなす駆動電極4A、4Bは、画素電極部4APと電極線部4BLとが対向し、画素電極部4BPと電極線部4ALとが対向するよう、交互に入り組むように配置されている。このガラス基板2における駆動電極4A、4Bを形成した面には、配向膜5が少なくとも表示領域全体に亘って形成されている。

【0004】 一方、ガラス基板3におけるガラス基板2と対向する面には、上記した駆動電極4A、4Bと交差する方向に沿って表示領域を横断する複数の平行な走査電極6が形成されている。なお、これら走査電極6は、例えばITO(indium tin oxide)などの透明導電性材料で形成されている。図8に示すように、走査電極6は、ガラス基板2側のそれぞれの対をなす駆動電極4A、4Bに対して2つの隣接する画素電極部4AP、4BPと対向するような幅寸法に設定されている。このガラス基板3における走査電極6を含む、ガラス基板2と対向する面には配向膜7が、少なくとも表示領域全体に亘って形成されている。

【0005】 そして、対向するガラス基板2、3間に、表示領域を取り囲むように図示しないシール材が配置・形成され、両ガラス基板2、3とシール材とで形成される空隙に液晶8が封止されて液晶表示装置1が大略構成されている。

【0006】

【発明が解決しようとする課題】 しかしながら、上記した液晶表示装置1では、駆動電極4A、4Bの凹凸形状を利用して互いに入り組む電極構造であるため、走査電極6に対向する、互いに隣接する画素電極部4AP、4BPの幅寸法が対向する電極線部4BL、4ALの幅寸法により制約を受けるため開口率をさらに大きくすることが困難であった。また、開口率を大きくしようと電極線部4AL、4BLを細くせざるを得ず、駆動電極4A、4Bの電気抵抗が大きくなるという問題点があった。また、このような電極構造では、3本以上の群をなす駆動電極が同一の走査電極に3つ以上の画素電極部で対向する多重マトリクス構成とすることが構造的に困

難であった。さらに、電極線部4AL、4BLと走査電極6との間の液晶8が駆動されて不要な表示が行われるという問題点があった。

【0007】そこで、本発明が解決しようとする課題は、多重化される電極数を増加できるとともに、開口率を高くすることができ、しかも表示品質の良好な電気光学装置を得るには、どのような手段を講じればよいかという点にある。

【0008】

【課題を解決するための手段】上記した課題を解決するため、本発明で講じる手段は、相対向して対をなす第1の基板と第2の基板のうち、少なくとも一方が表示用光に対して透過性を有し、第1の基板の対向内側面に所定方向に沿って互いに平行をなす複数本で群を構成する第1の電極が複数群、互いに略平行に形成され、かつ第2の基板の対向内側面に第1の電極に交差する方向に沿って互いに略平行な複数の第2の電極が形成され、第1の基板と第2の基板との間に電気光学材料層が介在された電気光学装置であって、第1の電極を含む第1の基板の対向内側面に層間絶縁膜が形成され、第2の電極と第1の電極の群との、それぞれの交差位置における層間絶縁膜の表面に、群を構成する第1の電極と同数の画素電極の群が、第2の電極と対向するように配置、形成され、かつ第1の電極の群の延在方向に沿って画素電極の群が列をなすとともに、それぞれの交差位置で、画素電極の群と第1の電極の群のうちのそれぞれ対応するものどうしが、層間絶縁膜に形成されたスルーホールを介して接続されていることを特徴とする。

【0009】このような構成の本発明によれば、群をなす第1の電極と第2の電極とが交差する位置の層間絶縁膜の表面に第2の電極と対向する複数の画素電極が配置され、これら画素電極に対応する第1の電極が層間絶縁膜に形成されたスルーホールを介して画素電極に接続されているため、第1の電極の形成スペースにより画素電極の形成スペースが規制されることはなく、画素形成領域の面積（表示領域の面積を総画素数で割った面積）に画素電極面積を近づけることができ、すなわち高い開口率を実現することが可能となる。加えて、本発明では画素電極が第1の電極の影響を受けないため、画素電極の形状を自由に設定できる。また、第1の電極を画素電極の幅寸法内で第2の電極と第1の電極の群の交差位置

（層間絶縁膜上）に画素電極を複数（特に3以上）形成することが構造的に容易であり、マトリクスの多重化を図ることができる。さらに、第1の電極が層間絶縁膜の下に形成されるため、第1の電極が直接、電気光学材料へ電気光学作用を与えることを防止することができ、表示品質の向上を図ることができる。

【0010】また、本発明は、電気光学材料層として液晶を第1の基板と第2の基板との間に介在させることができ、このように液晶を電気光学材料として用いる

ことにより、開口率が高く表示品質の良好な液晶表示装置を実現することができる。

【0011】さらに、本発明は、画素電極が表示用光に対して反射性を有する導電性材料で形成され、第2の基板および第2の電極は表示用光に対して透過性を有することことが好ましい。このような構成の本発明によれば、反射型液晶表示装置の多重マトリクス化を容易にすることができる。すなわち、第2の電極と交差する第1の電極の群を構成するそれぞれの第1の電極が交差位置の画素電極に接続されているため、所定の第1の電極へ選択的に電圧印加を行うことで、第2の電極と所定の画素電極との間に電界を発生させることができ、これら第2の電極と画素電極との間に介在される液晶を駆動することができる。特に、本発明では、第1の電極が層間絶縁膜の下に形成されるため、第1の電極が直接、液晶の配向を変化させる作用を有しないため、適正な表示に不要な反射光が生じるのを防止することができ、表示品質を向上することができる。

【0012】また、本発明は、画素電極、層間絶縁膜、第1の電極、第1の基板、第2の基板、および第2の電極が表示用光に対して透過性を有するとともに、第1の基板の後方に照明手段を備えることにより、多重マトリクス構成の透過型液晶表示装置を実現することができる。具体的には、例えば画素電極をITO、層間絶縁膜を酸化シリコン(SiO_x)や窒化シリコン(SiN_x)、後配線をITO、第1の基板を透明なガラスや合成樹脂で形成することができる。

【0013】さらに、本発明は、第2の電極が走査電極であり、第1の電極が駆動電極であることが好ましい。この構成の本発明によれば、走査電極の数を増加させることなく駆動電極数を増やすことができ、駆動制御が簡単で高精細な電気光学装置を実現することができる。

【0014】

【発明の実施の形態】以下、この発明に係る電気光学装置の詳細を図面に示す実施形態に基づいて説明する。

【0015】（実施形態1）図1～図3は、本発明に係る電気光学装置を反射型の液晶表示装置に適用した実施形態1を示している。本実施形態1の液晶表示装置は3重マトリクス構成されている。なお、図1は本実施形態1の液晶表示装置の電極構造を示す平面図、図2は図1のA-A断面に相当する断面図、図3は図1のB-B断面に相当する断面図である。

【0016】本実施形態1の液晶表示装置11は、図2および図3に示すように、対向する一対の、第1の基板としての後ガラス基板12と、第2の基板としての前ガラス基板13とを備え、後ガラス基板12の前ガラス基板13と対向する面側に列方向（図1中矢印yで示す方向）に沿って互いに平行に形成された、第1の電極としての複数群の駆動電極14（14A、14B、14C）

と、この駆動電極14に接続された反射画素電極15(15A、15B、15C)とが設けられ、前ガラス基板13の後ガラス基板12と対向する面側に行方向(図1中矢印xで示す方向)に沿って延在されて互いに平行に形成された第2の電極としての複数の走査電極16が設けられ、これら後ガラス基板12と前ガラス基板13との間に液晶17が封止されて大略構成されている。

【0017】ここで、後ガラス基板12側の構成を具体的に説明する。本実施形態1では、後基板として後ガラス基板12を用いたが、この後ガラス基板12は透明である必要はない。この後ガラス基板12の対向内側面(前ガラス基板13と対向する面)には、図1に示すように列方向(図中矢印yで示す)に沿って互いに平行に形成された、3本ずつの群をなす駆動電極14A、14B、14Cが複数群、互いに平行に形成されている。なお、本実施形態1では群を構成する駆動電極14A、14B、14Cは、列方向に並ぶ後記する反射画素電極15の下に収まるように間隔が設定されている。このようにストライプ状に駆動電極14が形成された後ガラス基板12の対向内側面には、これら駆動電極14を覆うように層間絶縁膜18が所定の膜厚に堆積されている。なお、この層間絶縁膜18としては、例えばにて形成される酸化シリコン(SiO_x)や窒化シリコン(SiNx)などを用いることができる。

【0018】そして、この層間絶縁膜18の上には、以下に説明する配置で反射画素電極15の列が複数、互いに平行に形成されている。すなわち、層間絶縁膜18の上に配置される反射画素電極15は、それぞれの駆動電極14の群(14A、14B、14C)の延在方向(列方向、矢印y方向)に沿って層間絶縁膜18の表面に列をなすように形成されている。その結果、それぞれの反射画素電極15の列は、前ガラス基板13側に平行に形成された走査電極16に対して、液晶17などを介して交差(直交)するように対向している。それぞれの走査電極16の幅域内には、列方向に配置された反射画素電極15の列のうち3つの反射画素電極15A、15B、15Cの群が収まるように対向・配置されている。このように群をなす3つの反射画素電極15A、15B、15Cは、走査電極16と、反射画素電極15の列とが交差する位置にそれぞれ配置されている。反射画素電極15の列は、順次走査電極16に対向する3つの反射画素電極15A、15B、15Cの順を繰り返しながら列方向に沿って表示領域を縦断するように設定されている。

【0019】これら反射画素電極15A、15B、15Cは、層間絶縁膜18の下に形成された3本の駆動電極14A、14B、14Cに対して、それぞれ対応する駆動電極14と、層間絶縁膜18に形成されたスルーホール19を介して接続されている。具体的には、反射画素電極15Aがスルーホール19Aを介して駆動電極14Aに接続され、反射画素電極15Bがスルーホール19

Bを介して駆動電極14Bに接続され、反射画素電極15Cがスルーホール19Cを介して駆動電極14Cに接続されている。

【0020】なお、このように層間絶縁膜18に形成したスルーホール19を介して下地駆動電極14と反射画素電極15とを接続する構造とするには、層間絶縁膜18の所定位置(各画素電極領域内)に、フォトリソグラフィー技術およびエッチング技術を用いてスルーホール19を開口してそれぞれの駆動電極14(14A、14B、14C)を露呈させた後、反射画素電極15を構成する材料金属(例えばアルミニウム、銀、クロムなど)をスペッタ法などを用いてスルーホール19の埋め込みと層間絶縁膜18上への堆積を行った後、フォトリソグラフィー技術およびエッチング技術を用いて反射画素電極15のバーニングを行うことで形成できる。また、スルーホール19内に埋め込みプラグを形成した後、画素電極材料を層間絶縁膜18上に堆積させ、次いで画素電極15のバーニングを行ってもよい。なお、この画素電極15(15A、15B、15C)のバーニングでは、画素電極どうしの間隔を極力狭く設定することで画素開口率を高めることができる。なお、このように画素電極15どうしの間隔を狭くしても、駆動電極14(14A、14B、14C)は層間絶縁膜18の下に形成されるため、画素電極15の形成領域を駆動電極14が干渉することがない。

【0021】このように複数列をなす画素電極15(15A、15B、15C)を含めて層間絶縁膜18上には、少なくとも表示領域全体に亘って後配向膜20が形成されている。

【0022】次に、上記した後ガラス基板12と対向する前ガラス基板13側の構成をより具体的に説明する。前ガラス基板13の対向内側面(後ガラス基板12と対向する面)には、上記した後ガラス基板12に形成された画素電極15のそれぞれの列と対向するように列方向に沿って画素電極15と略同一の幅寸法のカラーフィルタ21がストライプ状に形成されている。カラーフィルタ21は、赤用のカラーフィルタ21R、緑用のカラーフィルタ21G、青用のカラーフィルタ21Bの順で繰り返すように配置されている。これらカラーフィルタ21R、21G、21Bを含めて前ガラス基板13の対向内側面の少なくとも表示領域全体に亘って保護膜22が形成されている。保護膜22の表面には、上記した透明電極としての複数の走査電極16が行方向にストライプ状に形成されている。さらに、走査電極16を含む保護膜22の表面には、少なくとも表示領域全体に亘って前配向膜23が形成されている。

【0023】以上、後ガラス基板12側および前ガラス基板13側の構成を説明したが、これらは、表示領域を囲むように配置・形成された図示しないシール材を介して配向膜20、23どうしが所定のギャップを介して対

向するように貼り合わされ、後配向膜20と前配向膜23とシール材とで形成される間隙に液晶17が封止されて、液晶表示装置11が構成されている。

【0024】以上、本実施形態1の液晶表示装置11の構成について説明したが、本実施形態1においては、走査電極16と駆動電極14の群(14A、14B、14C)とが交差する領域にそれぞれの駆動電極14A、14B、14Cに対応する3つの画素電極15A、15B、15Cが対向するため、3重マトリクス構成を実現している。このように走査電極16と駆動電極14の群(14A、14B、14C)との交差領域に形成される画素電極15A、15B、15Cは駆動電極14A、14B、14Cに干渉を受けずに画素形成領域に近い面積まで大きくすることができるため、開口率を向上することができ、輝度の高い表示を行うことが可能となる。また、駆動電極14も画素電極15の干渉を受けないため、1本の走査電極16に対して多重化される駆動電極の本数を増やすことが可能となる。このように駆動電極本数の増加や開口率の向上を図ることができるために、高精細で良好な表示が行える多重マトリクス構成の反射型液晶表示装置を実現することができる。図2および図3は、緑用のカラーフィルタ21Gに入射した外光が、液晶17で変調されつつ反射画素電極15Bで反射されて表示光として出射する状態を示している。なお、本実施形態1においては、カラーフィルタ21R、21G、21Bをそれぞれ列方向に沿って形成したが行方向に沿ってストライプ状に形成してもよい。

【0025】(実施形態2)図4は、本発明に係る電気光学装置を透過型の液晶表示装置に適用した例を示している。なお、本実施形態2は、後ガラス基板12、駆動電極14、層間絶縁膜18、画素電極15が共に透明材料で構成され、後ガラス基板12の後方に照明装置としてのバックライトシステム24を備えた構成である点以外は、上記した実施形態1と同様であるため同一部分に同一の符号を付して説明を省略する。本実施形態2では、バックライトシステム24からの光を各画素部分で変調して所定のカラーフィルタ21を通して前方へ出射する。バックライトシステム24は、光源24Aと反射板24Bと導光板24Cなどを備えてなる。なお、本実施形態2の作用・効果は上記した実施形態1と同様である。

【0026】(実施形態3)図5～図7は、本発明に係る電気光学装置を反射型の液晶表示装置に適用した実施形態1の変形例である。図5は本実施形態3の液晶表示装置11の電極構成を示す平面図、図6は図5のC-C断面に相当する断面図、図7は図5のD-D断面に相当する断面図である。なお、本実施形態3は、駆動電極の群が2本の駆動電極14D、14Eで構成され、走査電極16と駆動電極群とが交差する対向位置に列方向に並ぶ2つの画素電極15D、15Eが走査電極16と対向

するように配置され、対応する画素電極15Dと駆動電極14Dとがスルーホール19Dで接続されるとともに、対応する画素電極15Eと駆動電極14Eとがスルーホール19Eで接続されたものである。また、前ガラス基板13側には、カラーフィルタを有しない構成となっている。なお、本実施形態3における他の構成は上記した実施形態1と同様であるため、同一部分に同一の符号を付して説明を省略する。

【0027】本実施形態3では、画素電極15(15D、15E)の行方向の幅域内に2本の駆動電極14(14D、14E)を配置するだけであるため、より幅寸法の長い駆動電極14を形成することができ、駆動電極14の低抵抗化を図ることができる。また、本実施形態3においても、層間絶縁膜18の下に駆動電極14を形成するためが、反射画素電極15D、15Eが駆動電極14の制約を受けず画素形成領域に対する画素電極15の面積占有率(開口率)を高めることができる。本実施形態3における他の作用・効果は、上記した実施形態1と同様である。

【0028】以上、実施形態1～実施形態3について説明したが、本発明に係る電気光学装置は、これらに限定されるものではなく、構成の要旨に付随する各種の変更が可能である。例えば、上記した実施形態1では3本で群をなす駆動電極14A、14B、14Cと備える構成としたが、4本以上の群をなす駆動電極とすることもできる。また、上記した各実施形態は電気光学材料として液晶17を用いた液晶表示装置に本発明を適用して説明したが、この他にエレクトロルミネッセンス材料を含む電荷輸送層や発光層などを備えたEL層を介在させた構成の電気光学装置としてもよい。この場合、画素電極は例えばIn-Mgなどの仕事関数の低いカソード材料で形成することが好ましく、走査電極としては例えばITOなどの仕事関数の高いアノード材料で形成することが好ましい。さらに、上記した各実施形態では、走査電極に対して駆動電極を多重化する構成としたが、駆動電極に対して走査電極を多重化する構成とすることも可能である。

【図面の簡単な説明】

【図1】本発明に係る電気光学装置を反射型液晶表示装置に適用した実施形態1の電極構成を示す平面図。

【図2】図1のA-A断面に相当する液晶表示装置の断面図。

【図3】図1のB-B断面に相当する液晶表示装置の断面図。

【図4】本発明に係る電気光学装置を透過型液晶表示装置に適用した実施形態2の断面図。

【図5】本発明に係る電気光学装置を反射型液晶表示装置に適用した実施形態3の電極構成を示す平面図。

【図6】図5のC-C断面に相当する液晶表示装置の断面図。

【図7】図5のD-D断面に相当する液晶表示装置の断面図。

【図8】従来の液晶表示装置の多重化マトリクス構成を示す電極の平面図。

【図9】図8のE-E断面に相当する液晶表示装置の断面図。

【図10】図8のF-F断面に相当する液晶表示装置の断面図。

【符号の説明】

1 1 液晶表示装置

1 2 後ガラス基板

1 3 前ガラス基板

1 4 (1 4 A、1 4 B、1 4 C、1 4 D、1 4 E) 駆動電極

1 5 (1 5 A、1 5 B、1 5 C、1 5 D、1 5 E) 画素電極

1 6 走査電極

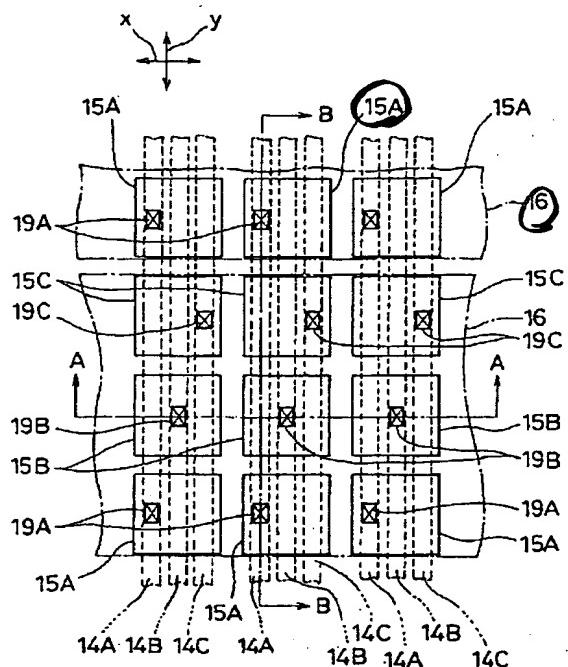
1 7 液晶

1 8 層間絶縁膜

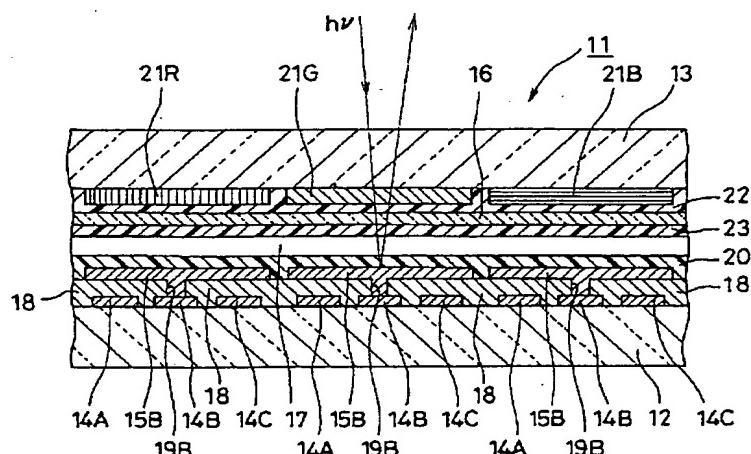
1 9 (1 9 A、1 9 B、1 9 C、1 9 D、1 9 E) ス

10 ルーホール

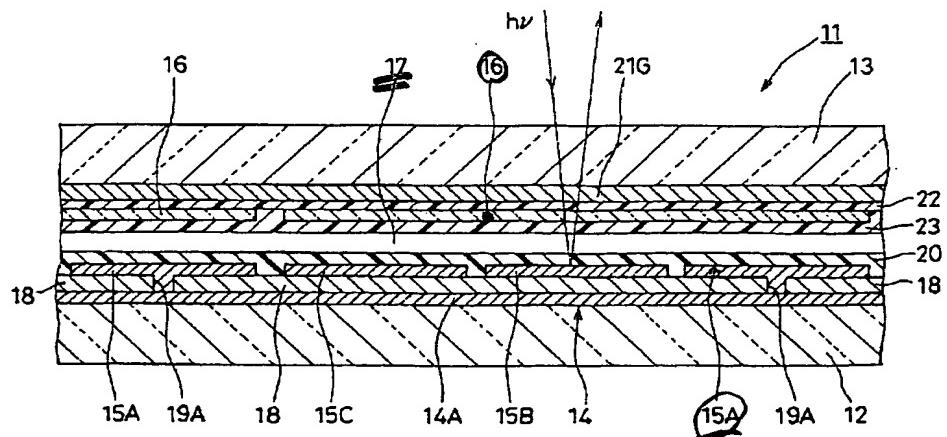
【図1】



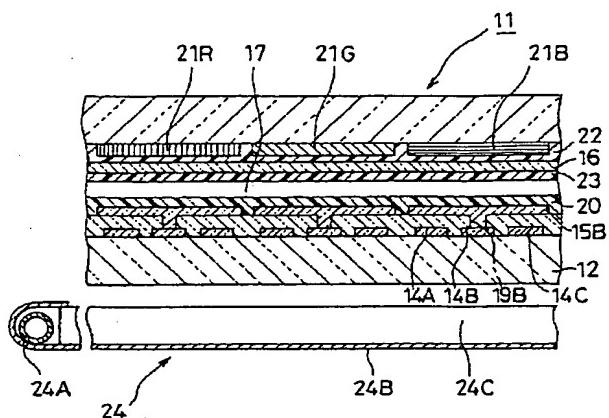
【図2】



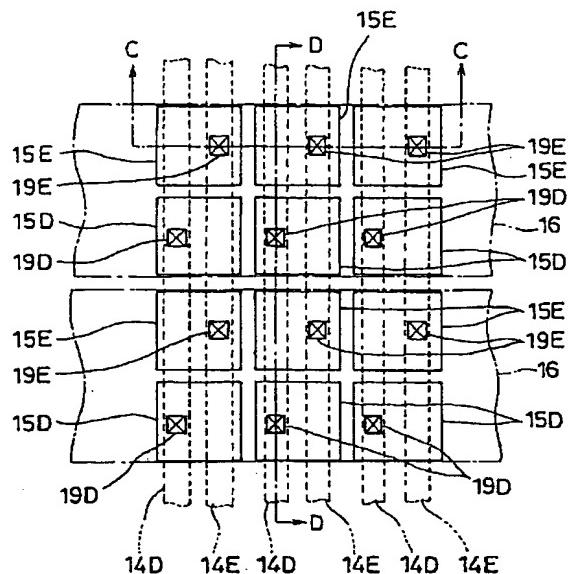
【図3】



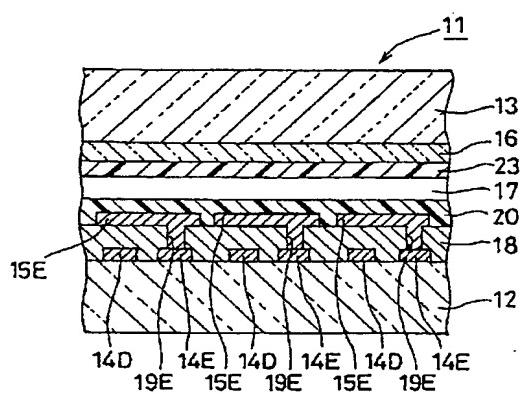
【図4】



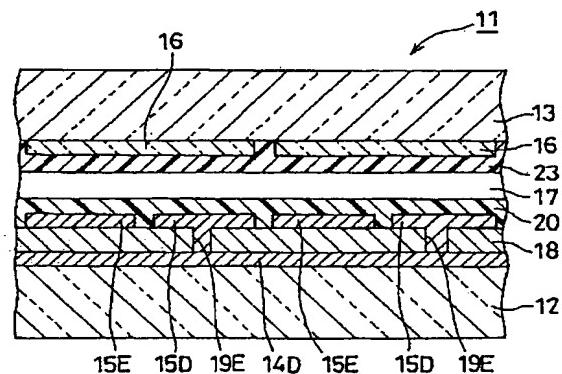
【図5】



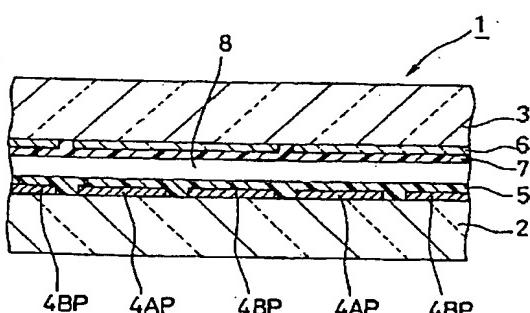
【図6】



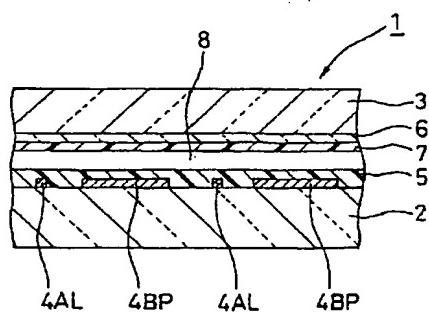
【図7】



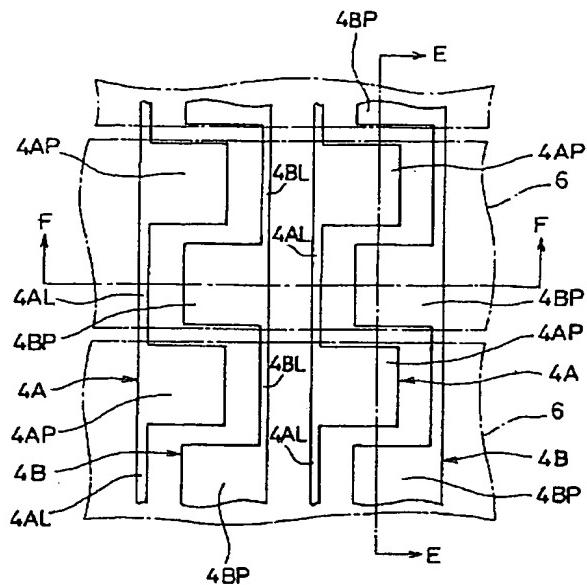
【図9】



【図10】



【図8】



PATENT ABSTRACTS OF JAPAN

(11) Publication number : 2000-221529

(43) Date of publication of application : 11.08.2000

(51) Int.CI. G02F 1/1343
G09F 9/30

(21) Application number : 11-025014 (71) Applicant : SEIKO EPSON CORP

(22) Date of filing : 02.02.1999 (72) Inventor : IINO SEIICHI

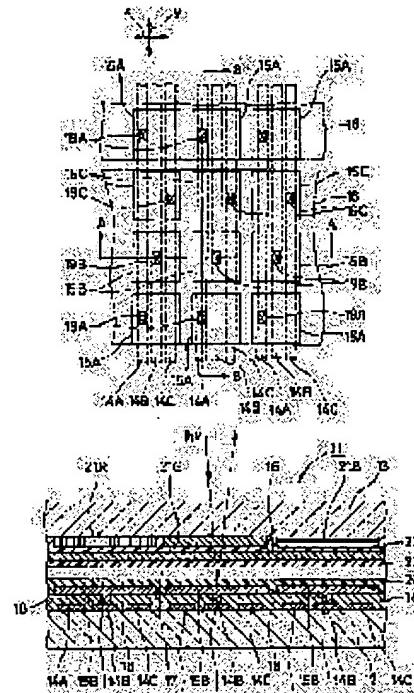
(54) ELECTRO-OPTIC DEVICE

(57) Abstract:

PROBLEM TO BE SOLVED: To provide an electro-optic device having good display quality with a high aperture ratio by increasing the number of the electrodes to be multiplexed.

SOLUTION: Plural scanning electrodes 16 formed in a stripe form are formed along a row direction on a front glass substrate 13 side and drive electrodes 14A, 14B and 14C constituting three groups are formed along a column direction on a rear glass substrate 12 side.

Interlayer insulating films 18 are formed on the opposite inner flank of the rear glass substrate 12 formed with the drive electrodes. Respective three pixel electrodes 15A, 15B and 15C are formed along the column direction on the surfaces of the interlayer insulating film 18 of the regions where the drive electrode groups face the scanning electrodes 16. The drive electrodes 14A, 14B and 14C corresponding to these pixel electrodes 15A, 15B and 15C are connected via through-holes 19A, 19B and 19C formed on the interlayer insulating films 18. Since the aperture ratio of the pixel electrodes 15 can be greatly improved and the number of the drive electrodes can be increased by such constitution, the drive controllability and the display quality can be improved.



LEGAL STATUS

[Date of request for examination] 03.07.2003
[Date of sending the examiner's decision of rejection]
[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]
[Date of final disposal for application]
[Patent number]
[Date of registration]
[Number of appeal against examiner's decision of rejection]
[Date of requesting appeal against examiner's decision of rejection]
[Date of extinction of right]

Copyright (C); 1998,2003 Japan Patent Office

CLAIMS

[Claim(s)]

[Claim 1] At least one side has permeability to the light for a display among the 1st substrate and the 2nd substrate which carry out phase opposite and make a pair. The 1st electrode which constitutes a group from two or more [it is mutually parallel to the opposite inside side of the 1st substrate of the above along the predetermined direction] Two or more groups, Two or more 2nd parallel electrodes are formed. the direction which is mutually formed in abbreviation parallel and intersects the 1st electrode of the above in the opposite inside side of the 2nd substrate of the above -- meeting -- mutual -- abbreviation -- It is electro-optics equipment with which the opto-electronics-material layer intervened between the 1st substrate of the above, and the 2nd substrate of the above. A layer insulation film is formed in the opposite inside side of the 1st substrate containing the 1st electrode of the above of the above. On the front face of the aforementioned layer insulation film in each intersection position with the group of the 2nd electrode of the above, and the 1st electrode of the above While being arranged and forming the group of the 1st electrode of the above which constitutes the aforementioned group, and the pixel electrode of the same number so that it may counter with the 2nd electrode of the above, and the group of the aforementioned pixel electrode making a train along the extension direction of the group of the 1st electrode of the above Electro-optics equipment characterized by connecting those to which it corresponds of the group of the aforementioned pixel electrode, and the groups of the 1st electrode of the above, respectively through the through hole formed in the aforementioned layer insulation film in each aforementioned intersection position.

[Claim 2] The aforementioned opto-electronics-material layer is electro-optics equipment according to claim 1 characterized by being liquid crystal.

[Claim 3] It is electro-optics equipment according to claim 2 which the aforementioned pixel electrode is formed with a conductive material which has reflection nature to the light for a display, and is characterized by the 2nd substrate of the above and the 2nd electrode of the above having permeability to the light for a display.

[Claim 4] The aforementioned pixel electrode, the aforementioned layer insulation film, the 1st electrode of the above, the 1st substrate of the above, the 2nd substrate of the above, and the 2nd electrode of the above are electro-optics equipment according to claim 2 characterized by having a lighting means behind the 1st substrate of the above while having permeability to the light for a display.

[Claim 5] It is electro-optics equipment according to claim 1 to 4 which the 1st electrode of the above is a drive electrode, and is characterized by the 2nd electrode of the above being a scanning electrode.

[Translation done.]

DETAILED DESCRIPTION

[Detailed Description of the Invention]

[0001]

[The technical field to which invention belongs] this invention relates to electro-optics equipments which have the electrode structure by which multiplex matrix composition was carried out, such as a liquid crystal display and an electroluminescence (EL) display, in more detail about electro-optics equipment.

[0002]

[Description of the Prior Art] Conventionally, as electro-optics equipment with which multiplex matrix composition of the electrode was carried out, the liquid crystal display 1 of double matrix composition as shown in drawing 8 - drawing 10 is known. The E-E cross section of drawing 8 and drawing 10 of the plan in which drawing 8 shows the electrode pattern of a liquid crystal display, and drawing 9 are the F-F cross sections of drawing 8. As shown in drawing 9 and drawing 10, this liquid crystal display 1 has the glass substrates 2 and 3 which carry out phase opposite.

[0003] Two or more pairs of drive electrodes 4A and 4B which extended in the direction which travels through a viewing area are formed in the glass substrate 3 in a glass substrate 2, and the field which counters in parallel. These drive electrodes 4A and 4B are formed with a conductive material which has light reflex nature, such as aluminum. As shown in drawing 8, drive electrode 4A is formed in the abbreviation ctenidium configuration where rectangle-like pixel polar-zone 4AP and electrode line part 4AL with narrow width of face have been arranged by turns along the extension direction, and irregularity is formed towards drive electrode 4B which makes a pair. That is, a crevice is equivalent to the portion in which electrode line part 4AL was formed, and heights are equivalent to the portion in which pixel polar-zone 4AP was formed. Similarly, electrode line part 4BL with narrow rectangle-like pixel polar-zone 4BP and width of face is formed in the abbreviation ctenidium configuration arranged by turns along the extension direction so that irregularity may be made towards drive electrode 4A to which drive electrode 4B also makes a pair. The drive electrodes 4A and 4B which make these couples are arranged so that pixel polar-zone 4AP and electrode line part 4BL may counter, and pixel polar-zone 4BP and electrode line part 4AL may counter, and it may become intricate by turns. At least, the orientation film 5 covers the whole viewing area, and is formed in the field in which the drive electrodes 4A and 4B in this glass substrate 2 were formed.

[0004] On the other hand, two or more parallel scanning electrodes 6 which cross a viewing area along the direction which intersects the above-mentioned drive electrodes 4A and 4B are formed in the glass substrate 2 in a glass substrate 3, and the field which counters. In addition, these scanning electrode 6 is formed with transparent conductivity material, such as ITO (indium tin oxide). As shown in drawing 8, the scanning electrode 6 is set as two adjoining pixel polar-zone 4APs, 4BP, and a width-of-face size that counters to the drive electrodes 4A and 4B which make each pair by the side of a glass substrate 2. At least, the orientation film 7 covers the whole viewing area, and is formed in the glass substrate 2 and the field which counters containing the scanning electrode 6 in this glass substrate 3.

[0005] And liquid crystal 8 is closed by the opening by which the sealant which is not illustrated so that a viewing area may be surrounded is arranged and formed, and is formed by both the glass substrates 2 and 3 and the sealant between the glass substrate 2 which counters, and 3, and profile composition of the liquid crystal display 1 is carried out.

[0006]

[Problem(s) to be Solved by the Invention] However, in order to receive restrictions with the width-of-face size of electrode line part 4BL and 4AL which the width-of-face size of pixel polar-zone 4AP and 4BP which counters the scanning electrode 6, and which adjoins mutually counters in the above-mentioned liquid crystal display 1 since it is the electrode structure which becomes intricate mutually using the shape of toothing of the drive electrodes 4A and 4B, it was difficult to enlarge a numerical aperture further. Moreover, when it was going to enlarge the numerical aperture, about electrode line part 4AL and 4BL, a thin kink colander was not obtained but there was a trouble that the electric

resistance of the drive electrodes 4A and 4B became large. Moreover, it was structurally difficult to consider as the multiplex matrix composition in which the drive electrode which makes three or more groups counters the same scanning electrode by three or more pixel polar zone with such electrode structure. Furthermore, there was a trouble that the liquid crystal 8 between electrode line part 4AL, 4BL, and the scanning electrode 6 drove, and an unnecessary display was performed.

[0007] Then, the technical problem which this invention tends to solve is in the point what means should be provided, in order to be able to make a numerical aperture high and to obtain the good electro-optics equipment of display quality moreover, while being able to increase the number of electrodes multiplexed.

[0008]

[Means for Solving the Problem] In order to solve the above-mentioned technical problem, the means provided by this invention At least one side has permeability to the light for a display among the 1st substrate and the 2nd substrate which carry out phase opposite and make a pair. The 1st electrode which constitutes a group from two or more [it is mutually parallel to the opposite medial surface of the 1st substrate along the predetermined direction] Two or more groups, Two or more 2nd parallel electrodes are formed. the direction which is mutually formed in abbreviation parallel and intersects the 1st electrode at the opposite medial surface of the 2nd substrate -- meeting -- mutual -- abbreviation -- It is electro-optics equipment with which the opto-electronics-material layer intervened between the 1st substrate and the 2nd substrate. A layer insulation film is formed in the opposite medial surface of the 1st substrate containing the 1st electrode. On the front face of the layer insulation film in each intersection position with the group of the 2nd electrode and the 1st electrode While being arranged and forming the group of the 1st electrode which constitutes a group, and the pixel electrode of the same number so that it may counter with the 2nd electrode, and the group of a pixel electrode making a train along the extension direction of the group of the 1st electrode It is characterized by connecting those to which it corresponds of the group of a pixel electrode, and the groups of the 1st electrode, respectively through the through hole formed in the layer insulation film in each intersection position.

[0009] According to this invention of such composition, the 2nd electrode and two or more pixel electrodes which counter are arranged on the front face of the layer insulation film of the position where the 1st electrode which makes a group, and the 2nd electrode cross. Since the 1st electrode corresponding to these pixel electrode is connected to the pixel electrode through the through hole formed in the layer insulation film, It becomes possible for the formation space of a pixel electrode not to be regulated by the formation space of the 1st electrode, and to be able to bring pixel electrode area close to the area (area which divided the area of a viewing area by the total number of pixels) of a pixel formation field, namely, to realize a high numerical aperture. In addition, in this invention, since a pixel electrode is not influenced of the 1st electrode, the configuration of a pixel electrode can be set up freely. Moreover, it is structurally easy to carry out two or more (3 or more [Especially]) formation of the pixel electrode for the 1st electrode within the width-of-face size of a pixel electrode in the intersection position (on a layer insulation film) of the group of the 2nd electrode and the 1st electrode, and multiplexing of a matrix can be attained. Furthermore, since the 1st electrode is formed in the bottom of a layer insulation film, it can prevent that the 1st electrode gives an electro-optics operation to an opto electronics material directly, and improvement in display quality can be aimed at.

[0010] Moreover, as for this invention, it is desirable to make liquid crystal intervene between the 1st substrate and the 2nd substrate as an opto-electronics-material layer. Thus, by using liquid crystal as an opto electronics material, a numerical aperture can realize the good high liquid crystal display of display quality.

[0011] furthermore, the thing for which this invention is formed with a conductive material into which a pixel electrode has reflection nature to the light for a display, and the 2nd substrate and the 2nd electrode have permeability to the light for a display -- things are desirable According to this invention of such composition, multiplex matrix-ization of a reflected type liquid crystal display can be made easy. Since each 1st electrode which constitutes the group of the 2nd electrode and the 1st crossing electrode is connected to the pixel electrode of an intersection position, by namely, the thing for which voltage

impression is alternatively performed to the 1st predetermined electrode. Electric field can be generated between the 2nd electrode and a predetermined pixel electrode, and the liquid crystal which intervenes between these 2nd electrodes and a pixel electrode can be driven. Especially, in this invention, since it does not have the operation to which the 1st electrode changes the orientation of liquid crystal directly since the 1st electrode is formed in the bottom of a layer insulation film, it can prevent that the unnecessary reflected light arises in a proper display, and display quality can be improved.

[0012] Moreover, this invention can realize the penetrated type liquid crystal display of multiplex matrix composition by having a lighting means behind the 1st substrate while a pixel electrode, a layer insulation film, the 1st electrode, the 1st substrate, the 2nd substrate, and the 2nd electrode have permeability to the light for a display. Specifically, a silicon oxide (SiO_x), a silicon nitride (SiN_x), and post-wiring can be formed by ITO, and the 1st substrate can be formed [a pixel electrode] for ITO and a layer insulation film by transparent glass and transparent synthetic resin.

[0013] Furthermore, as for this invention, it is desirable that the 2nd electrode is a scanning electrode and the 1st electrode is a drive electrode. According to this invention of such composition, the number of drive electrodes can be increased without making the number of scanning electrodes increase, and drive control can realize easy and high definition electro-optics equipment.

[0014]

[Embodiments of the Invention] It explains based on the operation form which shows the detail of the electro-optics equipment concerning this invention hereafter to a drawing.

[0015] (Operation form 1) Drawing 1 - drawing 3 show the operation form 1 which applied the electro-optics equipment concerning this invention to the reflected type liquid crystal display. 3-fold matrix composition of the liquid crystal display of this operation form 1 is carried out. In addition, the plan in which drawing 1 shows the electrode structure of the liquid crystal display of this operation form 1, the cross section with which drawing 2 is equivalent to the A-A cross section of drawing 1, and drawing 3 are the cross sections equivalent to the B-B cross section of drawing 1.

[0016] As the liquid crystal display 11 of this operation gestalt 1 is shown in drawing 2 and drawing 3 It has the back glass substrate 12 as the 1st substrate of the couple which counters, and the front glass substrate 13 as the 2nd substrate. The front glass substrate 13 of the back glass substrate 12, and the drive electrode 14 (14A, 14B, 14C) of two or more groups as the 1st electrode mutually formed in the field side which counters in parallel along the direction of a train (direction shown by the drawing 1 Nakaya mark y), the reflective pixel electrode 15 (15A and 15B --) connected to this drive electrode 14 15C is prepared and two or more scanning electrodes 16 as the 2nd electrode which extended along with the line writing direction (direction shown by the drawing 1 Nakaya mark x), and was formed in the back glass-substrate [of the front glass substrate 13] 12 and field side which counters in parallel are formed. Profile composition of the liquid crystal 17 is closed and carried out between these after glass substrate 12 and the front glass substrate 13.

[0017] Here, the composition by the side of the back glass substrate 12 is explained concretely.

Although the back glass substrate 12 was used as a back substrate with this operation gestalt 1, a glass substrate 12 does not need to be transparent after this. the drive electrodes 14A, 14B, and 14C which were formed in the opposite medial surface (the front glass substrate 13 and field which counters) of a glass substrate 12 in parallel along the direction of a train (the arrow y in drawing shows) after this as shown in drawing 1 and which make every three groups -- two or more groups -- it is formed in parallel mutually In addition, the interval is set up so that the drive electrodes 14A, 14B, and 14C which constitute a group from this operation gestalt 1 may be settled in the bottom of the reflective pixel electrode 15 which is located in a line in the direction of a train and which carries out a postscript. Thus, the layer insulation film 18 has accumulated on predetermined thickness so that these drive electrode 14 may be covered in the opposite medial surface of the back glass substrate 12 with which the drive electrode 14 was formed in the shape of a stripe. In addition, a silicon oxide (SiO_x), a silicon nitride (SiN_x), etc. which are alike, for example and are formed as this layer insulation film 18 can be used. [0018] And on this layer insulation film 18, two or more trains of the reflective pixel electrode 15 are mutually formed in parallel by the arrangement explained below. That is, the reflective pixel electrode

15 arranged on the layer insulation film 18 is formed so that a train may be made on the front face of the layer insulation film 18 along the extension direction (the direction of a train, the direction of arrow y) of the group (14A, 14B, 14C) of each drive electrode 14. Consequently, to the scanning electrode 16 formed in parallel with the front glass-substrate 13 side, the train of each reflective pixel electrode 15 has countered so that it may cross through liquid crystal 17 etc. (rectangular cross). It is countered and arranged so that the group of three reflective pixel electrodes 15A, 15B, and 15C may be settled within the width of face of each scanning electrode 16 among the trains of the reflective pixel electrode 15 arranged in the direction of a train. Thus, three reflective pixel electrodes 15A, 15B, and 15C which make a group are arranged in the position where the scanning electrode 16 and the train of the reflective pixel electrode 15 cross, respectively. Repeating the order of three reflective pixel electrodes 15A, 15B, and 15C which counter the sequential-scanning electrode 16, the train of the reflective pixel electrode 15 is set up so that it may travel through a viewing area along the direction of a train.

[0019] These reflective pixel electrodes 15A, 15B, and 15C are connected with the drive electrode 14 which corresponds, respectively through the through hole 19 formed in the layer insulation film 18 to three drive electrodes 14A, 14B, and 14C formed in the bottom of the layer insulation film 18.

Specifically, reflective pixel electrode 15A is connected to drive electrode 14A through through hole 19A, reflective pixel electrode 15B is connected to drive electrode 14B through through hole 19B, and reflective pixel electrode 15C is connected to drive electrode 14C through through hole 19C.

[0020] In addition, in order to consider as the structure of connecting the ground drive electrode 14 and the reflective pixel electrode 15 through the through hole 19 formed in the layer insulation film 18 in this way the predetermined position (inside of each pixel electrode field) of the layer insulation film 18 - photo lithography technology and etching technology -- using -- a through hole 19 -- opening -- carrying out -- each drive electrode 14 (14A --) the material metal (for example, aluminum --) which constitutes the reflective pixel electrode 15 after making 14B and 14C expose After performing deposition of a up to [the embedding of a through hole 19, and the layer insulation film 18] for silver, chromium, etc. using a spatter etc., it can form by performing patterning of the reflective pixel electrode 15 using photo lithography technology and etching technology. Moreover, after embedding in a through hole 19 and forming a plug, a pixel electrode material is made to deposit on the layer insulation film 18, and, subsequently patterning of the pixel electrode 15 may be performed. In addition, patterning of this pixel electrode 15 (15A, 15B, 15C) can raise a pixel numerical aperture by setting up the interval of pixel electrodes narrowly as much as possible. In addition, even if it narrows the interval of pixel electrode 15 in this way, since the drive electrode 14 (14A, 14B, 14C) is formed in the bottom of the layer insulation film 18, the drive electrode 14 does not interfere in the formation field of the pixel electrode 15.

[0021] Thus, including the pixel electrode 15 (15A, 15B, 15C) which makes two or more trains, on the layer insulation film 18, the whole viewing area is covered at least and the back orientation film 20 is formed.

[0022] Next, after describing above, the composition by the side of a glass substrate 12 and the front glass substrate 13 which counters is explained more concretely. the opposite medial surface (the back glass substrate 12 and field which counters) of the front glass substrate 13 is countered with each train of the pixel electrode 15 formed in the glass substrate 12, after describing above -- as -- the direction of a train -- meeting -- the pixel electrode 15 and abbreviation -- the light filter 21 of the same width-of-face size is formed in the shape of a stripe The light filter 21 is arranged so that it may repeat in order of light-filter 21R for red, light-filter 21G for green, and light-filter 21B for blue. Including these light filters 21R, 21G, and 21B, even if there are few opposite medial surfaces of the front glass substrate 13, the whole viewing area is covered, and the protective coat 22 is formed. Two or more above-mentioned scanning electrodes 16 as a transparent electrode are formed in the front face of a protective coat 22 in the shape of a stripe at the line writing direction. Furthermore, the whole viewing area is covered at least and the last orientation film 23 is formed in the front face of the protective coat 22 containing the scanning electrode 16.

[0023] As mentioned above, although the composition by the side of the back glass substrate 12 and the

front glass substrate 13 was explained, liquid crystal 17 is closed by the gap which these are stuck as countered through a predetermined gap through the sealant which was arranged and formed so that a viewing area might be surrounded, and which is not illustrated in the orientation film 20 and 23, and is formed by the back orientation film 20, the last orientation film 23, and the sealant, and the liquid crystal display 11 is constituted.

[0024] As mentioned above, in this operation gestalt 1, although the composition of the liquid crystal display 11 of this operation gestalt 1 was explained, in order that three pixel electrodes 15A, 15B, and 15C corresponding to each drive electrode 14A, 14B, and 14C may counter the field to which the group (14A, 14B, 14C) of the scanning electrode 16 and the drive electrode 14 crosses, 3-fold matrix composition is realized. Thus, since the pixel electrodes 15A, 15B, and 15C formed in an intersection field with the group (14A, 14B, 14C) of the scanning electrode 16 and the drive electrode 14 can be enlarged to the area near a pixel formation field, without receiving interference in the drive electrodes 14A, 14B, and 14C, a numerical aperture can be improved, and it becomes possible to perform the high display of brightness. Moreover, the drive electrode 14 also becomes possible [increasing the number of the drive electrode multiplexed to one scanning electrode 16] in order not to receive interference of the pixel electrode 15. Thus, since increase in a drive electrode number and improvement in a numerical aperture can be aimed at, the reflected type liquid crystal display of the multiplex matrix composition which can perform a highly minute and good display is realizable. Drawing 2 and drawing 3 show the state where it is reflected by reflective pixel electrode 15B, and the outdoor daylight which carried out incidence to light-filter 21G for green carries out outgoing radiation as a display light, becoming irregular by liquid crystal 17. In addition, in this operation gestalt 1, although light filters 21R, 21G, and 21B were formed along the direction of a train, respectively, along with a line writing direction, you may form in the shape of a stripe.

[0025] (Operation gestalt 2) Drawing 4 shows the example which applied the electro-optics equipment concerning this invention to the penetrated type liquid crystal display. In addition, the back glass substrate 12, the drive electrode 14, the layer insulation film 18, and the pixel electrode 15 consist of transparent materials, and except the point which is the composition equipped with the back light system 24 as a lighting system behind the back glass substrate 12, since both these operation gestalten 2 are the same as the above-mentioned operation gestalt 1, they give the same sign to the same portion, and omit explanation. With this operation gestalt 2, the light from the back light system 24 is modulated in each pixel portion, and outgoing radiation is carried out to the front through the predetermined light filter 21. The back light system 24 comes to have light source 24A, reflecting plate 24B, light guide plate 24C, etc. In addition, the operation and the effect of this operation gestalt 2 are the same as the above-mentioned operation gestalt 1.

[0026] (Operation gestalt 3) Drawing 5 - drawing 7 are the modifications of the operation gestalt 1 which applied the electro-optics equipment concerning this invention to the reflected type liquid crystal display. The plan in which drawing 5 shows the electrode composition of the liquid crystal display 11 of this operation gestalt 3, the cross section with which drawing 6 is equivalent to the C-C cross section of drawing 5 , and drawing 7 are the cross sections equivalent to the D-D cross section of drawing 5 . In addition, as for this operation gestalt 3, the group of a drive electrode consists of two drive electrodes 14D and 14E. Two pixel electrode 15D located in a line with the opposite position where the scanning electrode 16 and a drive electrode group cross in the direction of a train, It is arranged, and while corresponding pixel electrode 15D and corresponding drive electrode 14D are connected by through hole 19D, corresponding pixel electrode 15E and corresponding drive electrode 14E are connected by through hole 19E, so that 15E may counter with the scanning electrode 16. Moreover, it has the composition of not having a light filter at the front glass-substrate 13 side. In addition, since other composition in this operation gestalt 3 is the same as that of the above-mentioned operation gestalt 1, it gives the same sign to the same portion, and omits explanation.

[0027] With this operation gestalt 3, since two drive electrodes 14 (14D, 14E) are only arranged within the width of face of the line writing direction of the pixel electrode 15 (15D, 15E), the long drive electrode 14 of a width-of-face size can be formed more, and low resistance-ization of the drive

electrode 14 can be attained. Moreover, also in this operation gestalt 3, since the drive electrode 14 is formed in the bottom of the layer insulation film 18, the reflective pixel electrodes 15D and 15E cannot receive restrictions of the drive electrode 14, but can raise the area pulse duty factor (numerical aperture) of the pixel electrode 15 to a pixel formation field. Other operation and effects in this operation gestalt 3 are the same as the above-mentioned operation gestalt 1.

[0028] As mentioned above, although the operation gestalt 1 - the operation gestalt 3 were explained, various kinds of change which is not limited to these and accompanies the summary of composition is possible for the electro-optics equipment concerning this invention. For example, although considered as the drive electrodes 14A, 14B, and 14C which make a group by three, and the composition which it has with the above-mentioned operation gestalt 1, it can also consider as the drive electrode which makes four or more groups. Moreover, although each above-mentioned operation gestalt was explained to the liquid crystal display which used liquid crystal 17 as an opto electronics material with the application of this invention, it is good also as electro-optics equipment of composition of having made EL layer equipped with the charge transporting bed containing electroluminescence material, the luminous layer, etc. intervene. In this case, as for a pixel electrode, it is desirable to form with the low cathode material of work functions, such as In-Mg, and it is desirable to form with a high anode material of work functions, such as ITO, as a scanning electrode. Furthermore, although considered as the composition which multiplexes a drive electrode to a scanning electrode with each above-mentioned operation gestalt, it is also possible to consider as the composition which multiplexes a scanning electrode to a drive electrode.

[Translation done.]